


Features

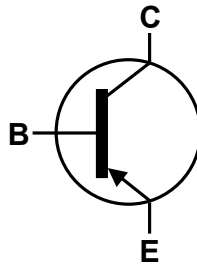
- $BV_{CEO} > -32V$
- $I_C = -2A$ high Continuous Current
- Low saturation voltage $V_{CE(sat)} < 800mV @ 2A$
- Complementary NPN Type: 2DD1766
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

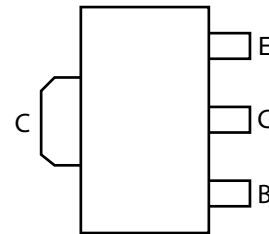
- Case: SOT89
- Case material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight: 0.052 grams (approximate)



Top View



Device Symbol



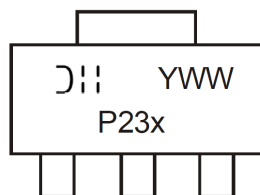
Pin Out – Top View

Ordering Information (Note 4)

| Part Number | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|--------------|---------|--------------------|-----------------|-------------------|
| 2DB1188P-13 | P23P | 13 | 12 | 2,500 |
| 2DB1188Q-13 | P23Q | 13 | 12 | 2,500 |
| 2DB1188Q-13R | P23Q | 13 | 12 | 4,000 |
| 2DB1188R-13 | P23R | 13 | 12 | 2,500 |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

Marking Information



P23x = Product Type Marking Code
 Where P23P = 2DB1188P
 P23Q = 2DB1188Q
 P23R = 2DB1188R

D = Manufacturers' code marking
 YWW = Date Code Marking
 Y = Last Digit of Year (ex: 1 = 2011)
 WW = Week Code (01 – 53)

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

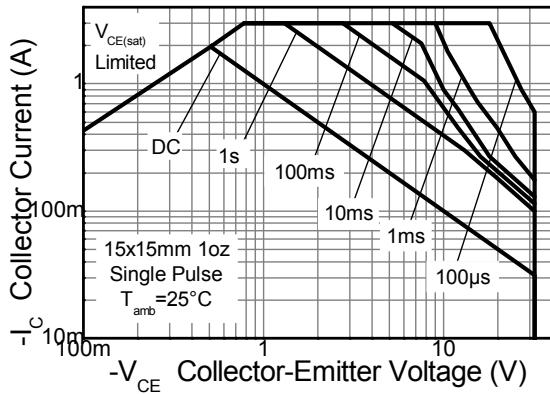
| Characteristic | Symbol | Value | Unit |
|------------------------------|-----------|-------|------|
| Collector-Base Voltage | V_{CBO} | -40 | V |
| Collector-Emitter Voltage | V_{CEO} | -32 | V |
| Emitter-Base Voltage | V_{EBO} | -6 | V |
| Continuous Collector Current | I_C | -2 | A |
| Peak Pulse Collector Current | I_{CM} | -3 | A |
| Base Current | I_B | -500 | mA |

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$ unless otherwise specified.)

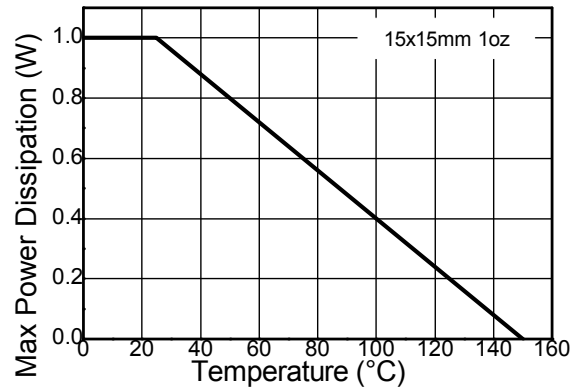
| Characteristic | Symbol | Value | Unit |
|--|-----------------|-------------|---------------------------|
| Power Dissipation (Note 5) | P_D | 1 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | $R_{\theta JA}$ | 125 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance, Junction to Leads (Note 6) | $R_{\theta JL}$ | 19 | $^\circ\text{C}/\text{W}$ |
| Operating and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

- Notes:
5. For a device surface mounted on 15mm x 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 6. Thermal resistance from junction to solder-point (on the exposed collector pad).

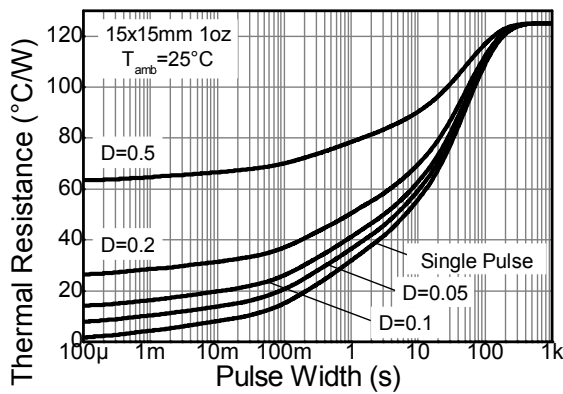
Thermal Characteristics and Derating Information



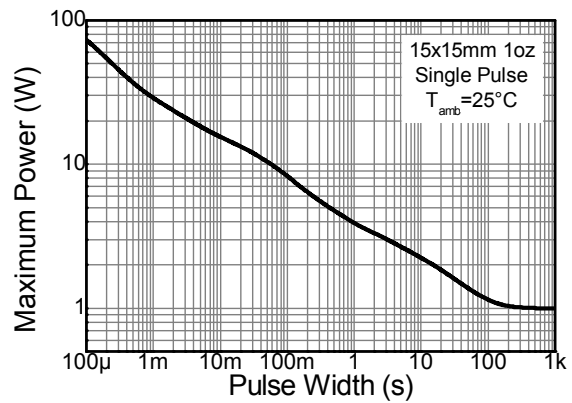
Safe Operating Area



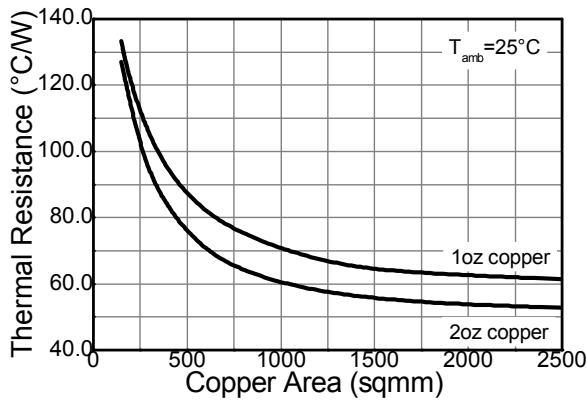
Derating Curve



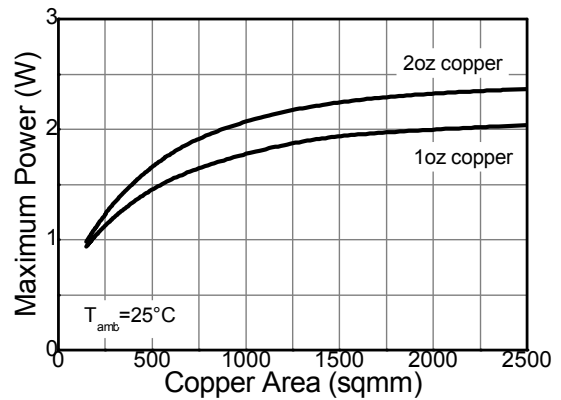
Transient Thermal Impedance



Pulse Power Dissipation



R_{TH} vs Area



P_D vs Area

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--------------------------------------|---------------|-----|-------|------|------|---|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Collector-Base Breakdown Voltage | BV_{CBO} | -40 | — | — | V | $I_C = -100\mu\text{A}, I_E = 0$ |
| Collector-Emitter Breakdown Voltage | BV_{CEO} | -32 | — | — | V | $I_C = -10\text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage | BV_{EBO} | -6 | — | — | V | $I_E = -100\mu\text{A}, I_C = 0$ |
| Collector Cutoff Current | I_{CBO} | — | — | -100 | nA | $V_{CB} = -20\text{V}, I_E = 0$ |
| Emitter Cutoff Current | I_{EBO} | — | — | -100 | nA | $V_{EB} = -5\text{V}, I_C = 0$ |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | — | -0.35 | -0.8 | V | $I_C = -2\text{A}, I_B = -0.2\text{A}$ |
| DC Current Gain | 2DB1188P | 82 | — | 180 | — | $V_{CE} = -3\text{V}, I_C = -0.5\text{A}$ |
| | 2DB1188Q | 120 | — | 270 | — | |
| | 2DB1188R | 180 | — | 390 | — | |
| SMALL SIGNAL CHARACTERISTICS | | | | | | |
| Current Gain-Bandwidth Product | f_T | — | 120 | — | MHz | $V_{CE} = -5\text{V}, I_C = -0.1\text{A}, f = 30\text{MHz}$ |
| Output Capacitance | C_{obo} | — | 20 | — | pF | $V_{CB} = -10\text{V}, f = 1\text{MHz}$ |

Notes: 7. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

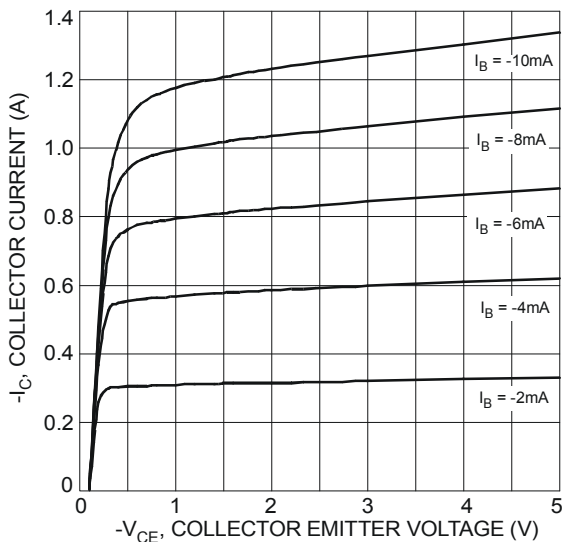


Figure 1. Typical Collector Current vs. Collector-Emitter Voltage

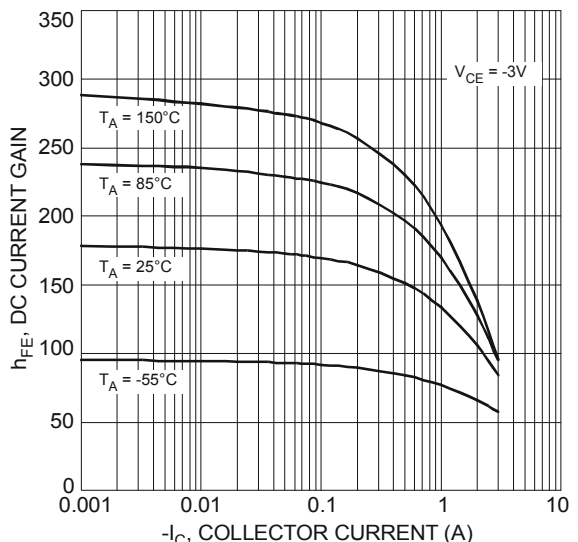


Figure 2. Typical DC Current Gain vs. Collector Current (2DB1188Q)

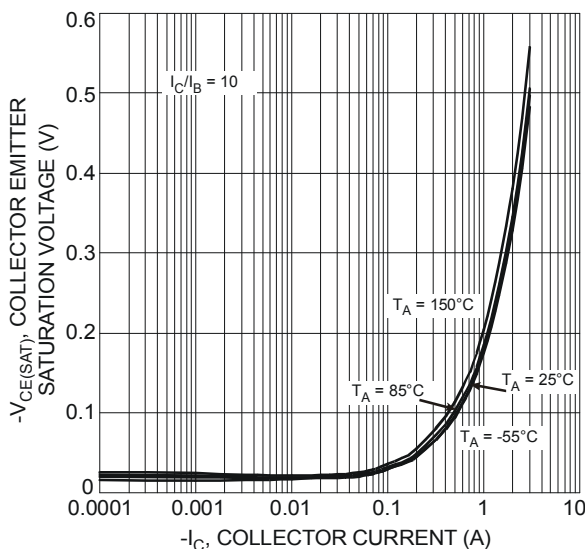


Figure 3. Typical Collector-Emitter Saturation Voltage vs. Collector Current

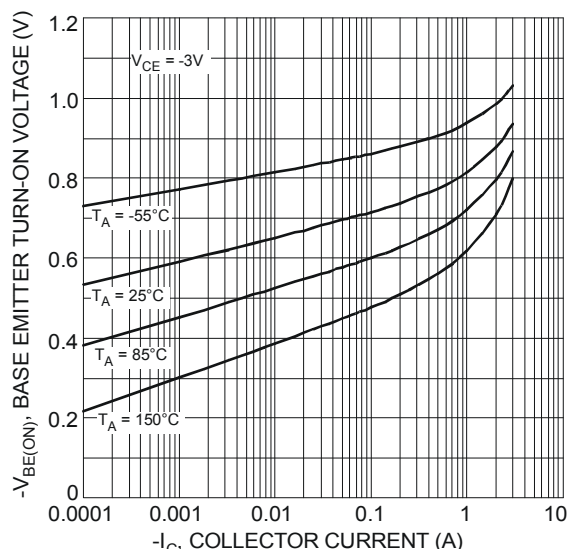


Figure 4. Typical Base-Emitter Turn-On Voltage vs. Collector Current

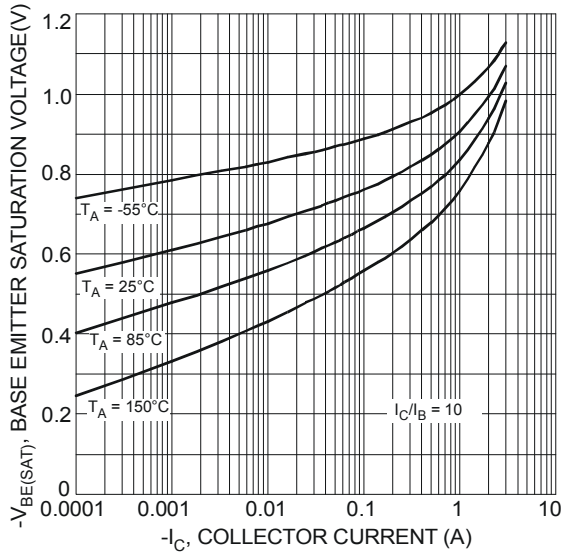


Figure 5. Typical Base-Emitter Saturation Voltage vs. Collector Current

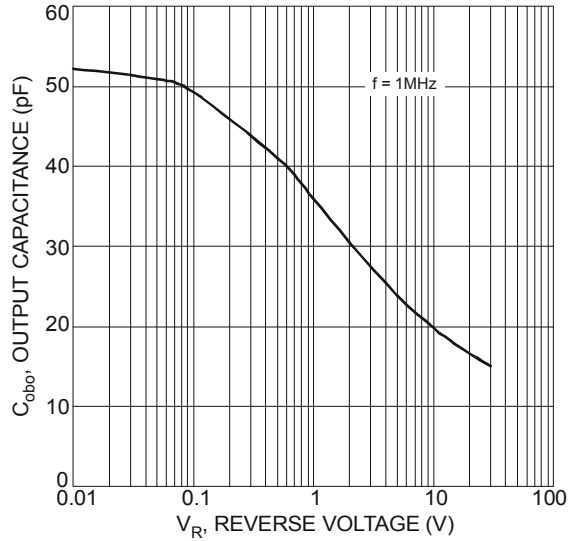


Figure 6. Typical Output Capacitance Characteristics

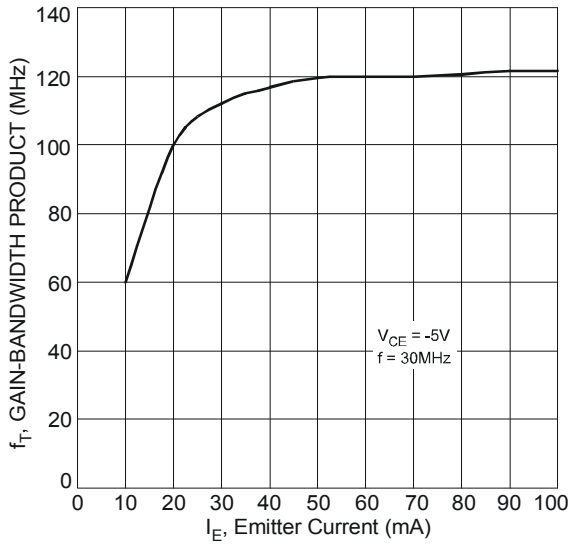
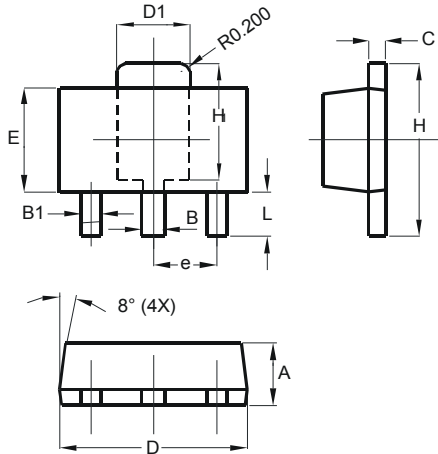


Figure 7. Typical Gain-Bandwidth Product vs. Emitter Current

Package Outline Dimensions

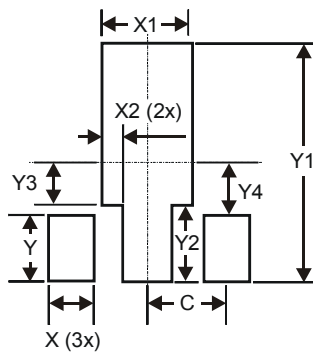
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| SOT89 | | |
|----------------------|----------|------|
| Dim | Min | Max |
| A | 1.40 | 1.60 |
| B | 0.44 | 0.62 |
| B1 | 0.35 | 0.54 |
| C | 0.35 | 0.44 |
| D | 4.40 | 4.60 |
| D1 | 1.62 | 1.83 |
| E | 2.29 | 2.60 |
| e | 1.50 Typ | |
| H | 3.94 | 4.25 |
| H1 | 2.63 | 2.93 |
| L | 0.89 | 1.20 |
| All Dimensions in mm | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| X | 0.900 |
| X1 | 1.733 |
| X2 | 0.416 |
| Y | 1.300 |
| Y1 | 4.600 |
| Y2 | 1.475 |
| Y3 | 0.950 |
| Y4 | 1.125 |
| C | 1.500 |

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

www.diodes.com

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru